Zhen Xu

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Education

University of Science and Technology of China **Sep. 2020 – Present**

Bachelor of Engineering in Electrical Engineering *Hefei, Anhui*

GPA: 3.42/4.3(85/100) **Ranking**: 25/76

Honors: Scholarship for Elite Class, Awarded to students admitted to the Elite Class

Relevant Coursework

- Design of Analog Integrated Circuits
- Digital Integrated Circuits Design
- The Practice of Chip Design
- Electromagnetic Field and Wave
- Linear Electronic Circuits
- Nonlinear Electronic Circuits
- Digital Logic Circuits
- Materials and physics of semiconductors

Research Experience

Integrated Nanoelectronics and X-Computing Lab, USTC **March 2023 – August 2023**

Research Intern *Hefei, Anhui*

- Conducted extensive research on two-dimensional semiconductor devices, focusing particularly on the manufacture and properties of MoS_2, and enhancing its interface properties using *hexagonal BN*.
- Participated in hands-on production activities for transistor devices, including scribing, lithography, lift-off, ALD, CVD, and more, to assess the properties of 2D semiconductor devices.
- Researched the development of 2T1C and 3T0C models for storage, as well as the integration of storage and computation.

Academic Activities

Design and Implementation of Integer Square Root Circuit | *Verilog HDL, Cadence* **May 2024**

- Designed an Integer Square Root circuit and its testbench using Verilog HDL.
- Conducted code simulation and netlist simulation using Cadence Incisive.
- Conducted logic synthesis and equivalence checking using Cadence Genus.
- Completed physical design of the chip using Cadence Innovus.

Design and Application of Operational Amplifier Circuits | *Cadence* **June 2024**

- Used Cadence to design an Open Loop Operational Amplifier that meets the following specifications: a Gain of $90dB$, a Unit Gain Bandwidth of approximately $80MHz$, a Phase Margin greater than $50°$, a Slew Rate greater than $25V/\mu s$, an Output Swing greater than $0.6V$, an output DC level of approximately $1V$, and a power consumption of less than $1mW$.
- Used this Operational Amplifier to design a Voltage Follower, which has a Bandwidth of $90MHz$ and good tracking characteristics within the range of $450mV$ to $1.8V$ (with a supply voltage of $1.8V$ and an allowable error of $10\mu V$).
- Used this Operational Amplifier to design an Inverting Amplifier with a Gain of -10, featuring excellent low-frequency gain and Bandwidth.

Skills

Languages: Chinese(native), English(TOEFL 106, GRE 323+3.5)
Programming Languages: Verilog HDL, C, LaTeX, MATLAB
Developer Tools: Cadence, Quartus, VS Code, MATLAB

Interests

Long-distance Running: Running long distances 4 to 5 times a week has become a habit that helps me stay focus at work.
Frontend Development: I created my personal homepage and developed a guide website for studying abroad.